

976 nm, 33 mW DBR Butterfly Laser with Isolator, PM Fiber



DBR976PN

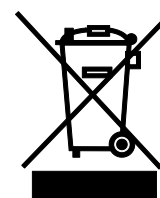
Description

Thorlabs' DBR976PN Distributed Bragg Reflector (DBR) laser is a single-frequency laser diode that is well-suited for low-noise pump applications, second harmonic generation, and time-resolved fluorescence spectroscopy. The DBR976PN includes an integrated optical isolator, thermoelectric cooler (TEC), thermistor, and monitor photodiode. It is packaged in a 14-pin butterfly package with PM980-XP polarization-maintaining optical fiber and an FC/APC connector with the connector key aligned to the slow axis of the fiber.

Specifications

DBR976PN ^a				
	Symbol	Min	Typical	Max
Center Wavelength	λ_c	974 nm	976 nm	978 nm
Laser Linewidth	$\Delta\nu$	-	5 MHz	-
Output Power CW @ I_{OP}	P_{OP}	25 mW	33 mW	-
Operating Current	I_{OP}	-	450 mA	-
Mode-Hop-Free Range ^b	$\Delta I_{\text{Mode-Hop-Free}}$	20 mA	-	-
SMSR in Mode-Hop-Free Range ^c	SMSR	30 dB	50 dB	-
30 dB BW in Mode-Hop-Free Range ^c	30 dB BW	-	-	0.3 nm
Threshold Current	I_{TH}	-	50 mA	-
Forward Voltage	V_F	-	2.0 V	2.5 V
Slope Efficiency	$\Delta P / \Delta I$	0.07 W/A	0.09 W/A	-
Current Tuning	$\Delta \lambda / \Delta I$	-	0.002 nm/mA	-
Temperature Tuning	$\Delta \lambda / \Delta T$	-	0.07 nm/°C	-
Monitor Diode Responsivity	I_{MON} / P	-	200 $\mu\text{A/mW}$	-
Polarization Extinction Ratio ^d	r_{ex}	-	16 dB	-
Internal Isolation	ISO	-	33 dB	-
TEC Current	I_{TEC}	-	0.24 A	-
TEC Voltage	V_{TEC}	-	0.31 V	-
Thermistor Resistance @ 25 °C	R_{TH}	-	10 k Ω	-

- $T_{CASE} = 25^\circ\text{C}$; $T_{CHIP} = 25^\circ\text{C}$.
- Continuous tuning range between mode hops.
- As measured with an optical spectrum analyzer (OSA) to empirically determine single frequency range. Laser 30 dB bandwidth and SMSR are subject to monochromator settings and OSA internal algorithms, and will differ from instrument to instrument.
- Ratio of transmitted light polarized along the fiber's slow axis to transmitted light polarized along the fast axis.

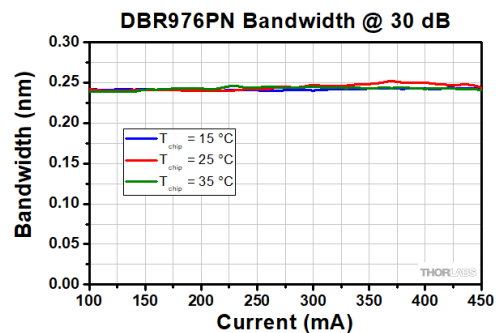
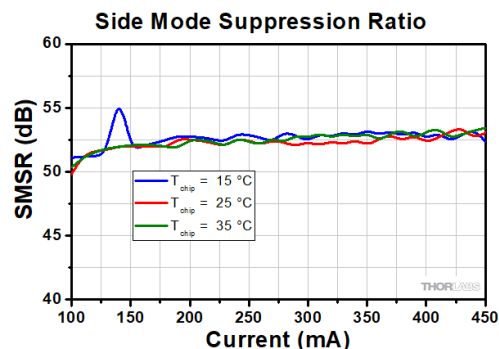
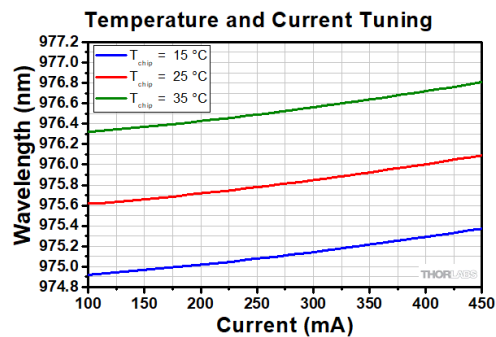
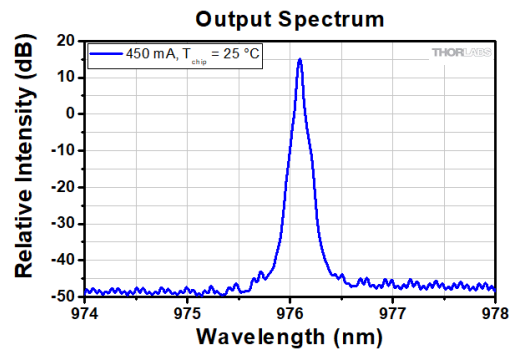
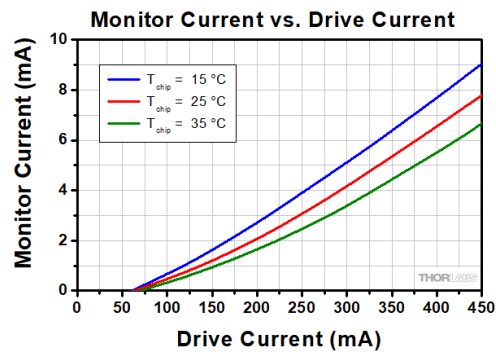
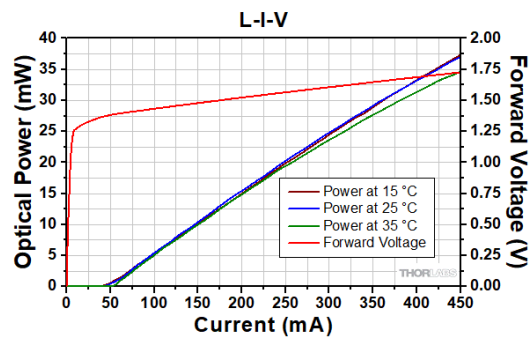


Absolute Max Ratings

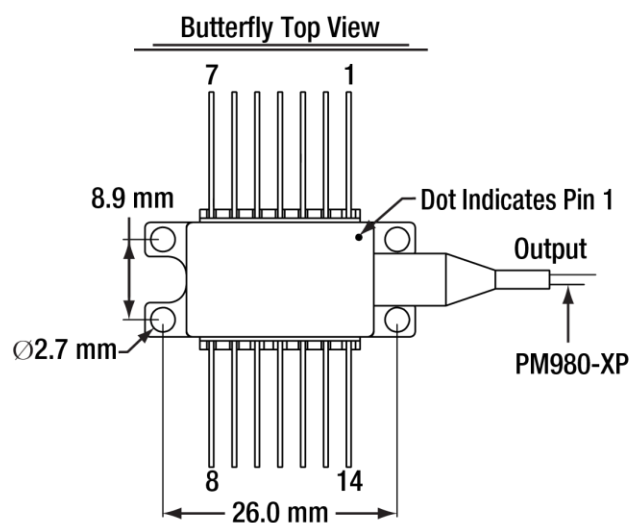
LD Reverse Voltage (Max)	2 V
Laser Current (Max) ^a	See Serialized Datasheet
Laser Power (Max) ^a	See Serialized Datasheet
TEC Current (Max)	3.0 A ($T_{CASE} = 20\text{ }^{\circ}\text{C}$); 2.9 A ($T_{CASE} = 70\text{ }^{\circ}\text{C}$)
TEC Voltage (Max)	3.6 V ($T_{CASE} = 20\text{ }^{\circ}\text{C}$); 4.4 V ($T_{CASE} = 70\text{ }^{\circ}\text{C}$)
PD Reverse Voltage (Max)	15 V
Operating Case Temperature	0 to 50 $^{\circ}\text{C}$
Operating Chip Temperature	10 to 40 $^{\circ}\text{C}$
Storage Temperature	-10 to 65 $^{\circ}\text{C}$

- a. Some devices will produce the max laser power before exceeding the typical operating current. Do not drive the laser diode beyond the absolute max laser current or power. Operating in this regime will cause damage to the device.

Typical Performance Plots



Drawings



PIN IDENTIFICATION

1. TEC +	14. TEC -
2. Thermistor	13. Case
3. PD Anode	12. NC
4. PD Cathode	11. LD Cathode
5. Thermistor	10. LD Anode
6. NC	9. NC
7. NC	8. NC

